# PART OBSOLETE - DISCONTINUED





**PI2DDR3212** 

1.35V/1.5V/1.8V 14 bit 2:1 DDR3/DDR4 Switch

#### **Features**

- → 14 bit 2:1 switch that supports DDR3 800 2133Mbps, DDR4 1600~4266 Mbps
- → VDD 1.35V/ 1.5V/ 1.8V
- → Flow through pinout option for easy layout
- → SEL and Global Enable
- $\rightarrow$  110 µA typ. operating current at 1.35V VDD.
- → High impedance and low Coff channel output when disabled or deselected
- → Low  $R_{ON}$ : 8Ω typical
- → 3dB Bandwidth: 3.3GHz
- → Low insertion loss: -0.7dB ( $0 \le f \le 1$  GHz)
- → Low return loss: -23dB ( $0 \le f \le 1$  GHz)
- → Low cross-talk for high speed channels: -25dB typ. (0<f<2GHz)
- → Low off-isolation: -28dB ( $0 \le f \le 1$  GHz)
- → Low bit-to-bit skew 20ps Max
- → ESD: 2KV HBM
- → POD\_12, SSTL\_12, SSTL\_135, SSTL\_15 or SSTL\_18 signaling
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- → Packaging (Pb-free and Green)
  - 52-pin, 3.5x9mm TQFN (ZL)
  - 48-pin, 4.5x4.5mm TFBGA (NC) pin compatible with CBTW28DD14

### **Application**

- → DDR3/DDR4 Memory Bus System
- → NVDIMM Module
- → Flash Memory Array sub system
- → High Speed multiplexing

### **Description**

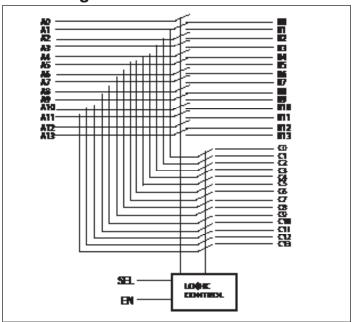
This 14-bit DDR3/DDR4 switch is designed for 1.35V/1.5V/1.8V supply voltage, POD\_12, SSTL\_135, SSTL\_15 or SSTL\_18 signaling and CMOS select input signals. It is designed for DDR3 or DDR4 memory bus with speed up to 5Gbps. It supports DDR3 800 2133Mbps and DDR4 1600~4266 Mbps.

PI2DDR3212 has a 1:2 demux or 2:1 mux topology. All 14-bit channels can be switched to one of the two ports simultaneously with the SEL input. This device also allows all ports to be disconnected.

PI2DDR3212 uses Diodes' proprietary high speed switch technology providing consistent high bandwidth across all channels, with very little insertion loss, cross-talk, and bit to bit skew.

It is available in a 52-pin TQFN 3.5x9mm package and 48-pin TFBGA 4.5x4.5mm package. The 48-pin version is pin compatible with CBTW28DD14.

# **Block Diagram**



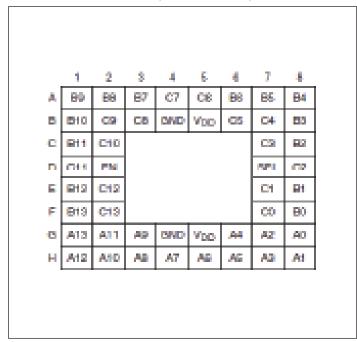
#### Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

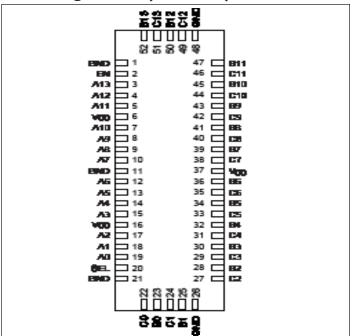




# Pin Configuration (48-TFBGA)



# **Pin Configuration (52-TQFN)**



# **Pin Description**

Pin Name	IO Type	Descriptions	
Vdd	Power	1.35V, 1.5V or 1.8V power supply.	
GND	Ground	1.35V, Ground connection	
A[0:13]	I/O	14-bit wide input/output, port A	
B[0:13]	I/O	4-bit wide input/output, port B	
C[0:13]	I/O	14-bit wide input/output, port C	
SEL	I	CMOS input for channel selection	
		CMOS input	
EN	I	When HIGH, connection is set using the SEL input signal	
		When LOW, all ports are mutually isolated	

### **Truth Table (SEL)**

SEL	Function	
0	Output B is selected	
1	Output C is selected	

# Truth Table (EN)

EN	Function	
1	Global Enable	
0	Global Disable	





# **Maximum Ratings**

(Above which useful life may be impaired. For user guidelines, not tested.)

Supply Voltage to Ground Potential	-0.3V to 2.5V
All Inputs	0.3V to VDD+0.3V
Ambient Operating Temperature	-10 to +85°C
Storage Temperature	
Junction Temperature	150°C
Soldering Temperature	260°C

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### **Recommended Operation Conditions**

Parameter	Min.	Тур.	Max.	Unit
Ambient Operating Temperature	-10		+85	°C
Power Supply Voltage (measured in respect to GND)		1.8	+2.0	V

#### **Static Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
$V_{DD}$	Supply Voltage		1.28	1.35/ 1.5/1.8	2	V
т	V. Comply Company	EN= HIGH; V <sub>DD</sub> =1.8V		220	350	μΑ
$\mid \mathbf{I}_{ ext{DD}} \mid$	V <sub>DD</sub> Supply Current	EN= LOW; V <sub>DD</sub> =1.8V		0.1	10	μΑ
т	W. C. I. C.	EN= HIGH; V <sub>DD</sub> =1.35V		110	200	μΑ
$\mid \mathbf{I}_{ ext{DD}} \mid$	V <sub>DD</sub> Supply Current	EN= LOW; V <sub>DD</sub> =1.35V		0.05	2	μΑ
Control Pi	ı (SEL, EN)					
$I_{\text{IH}}$	High level digital input current	$V_{IH}=V_{DD}$ , $V_{DD}=2.0V$			5	μΑ
$I_{IL}$	Low level digital input current	$V_{IL} = GND, V_{DD} = 2.0V$			5	μΑ
V <sub>IH</sub>	High level digital input voltage		0.8 *V <sub>DD</sub>			V
V <sub>IL</sub>	Low level digital input voltage				0.2*V <sub>DD</sub>	V
I/O Pin (A,	B,C)					
$C_{OFF}$	Switch OFF capacitance	$f = 1MHz; V_{I/O} = 0V$		1.1		pF
C <sub>on</sub>	Switch ON capacitance	$f = 1MHz; V_{I/O} = 0V$		2.1		pF





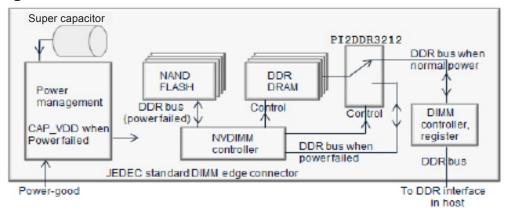
# **Dynamic Characteristics** (over recommended operating conditions unless otherwise noted)

Symbol	Parameter	<b>Test Conditions</b>	Min.	Typ. (1)	Max.	Units
tstartup	Startup time	Supply voltage valid or EN going HIGH to channels specified characteristics		5	10	116
trcfg	Reconfiguration time	SEL state change to channel specified operating characteristics		0.02	0.04	μs
tpd	Propagation delay	From A port to B port or C port or vice versa		60		ps
tsk	Skew time	From any output to any output		18	20	ps
V <sub>I</sub>	Input Voltage		-0.3		Vdd+0.3	V
В	Bandwidth	-3dB intercept		3.3		GHz
С	Crosstalk attenuation	Adjacent channels are on; $0 \le f \le 1 GHz$		-26		dB
I <sub>L</sub> Insertion Loss	$0 \le f \le 1GHz$		-0.7		dB	
	Insertion Loss	f = 2.5GHz		-2.5		dB
R <sub>L</sub>	Input Return Loss	$0 \le f \le 1GHz$		-23		dB
OI	Off Isolation	0 ≤ f ≤ 1 GHz		-28		dB

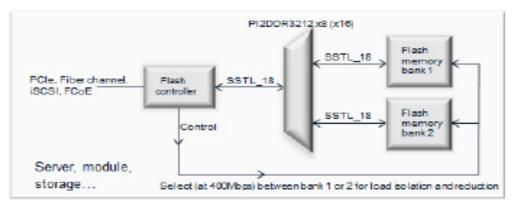




# **Application Diagram**



NVDIMM Application using PI2DDR3212



SSD, Flash Storage Application using PI2DDR3212





# **Part Marking**

ZL Package



YY: Year WW: Workweek 1st X: Assembly Code 2nd X: Fab Code NC Package



YY: Year

WW: Workweek

1st X: Assembly Code

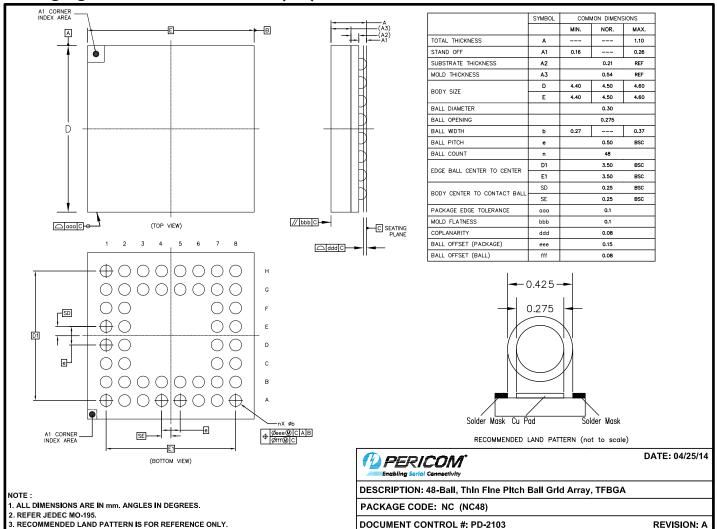
2nd X: Fab Code

Bar above fab code means Cu wire





### Packaging Mechanical: 48-TFBGA (NC)

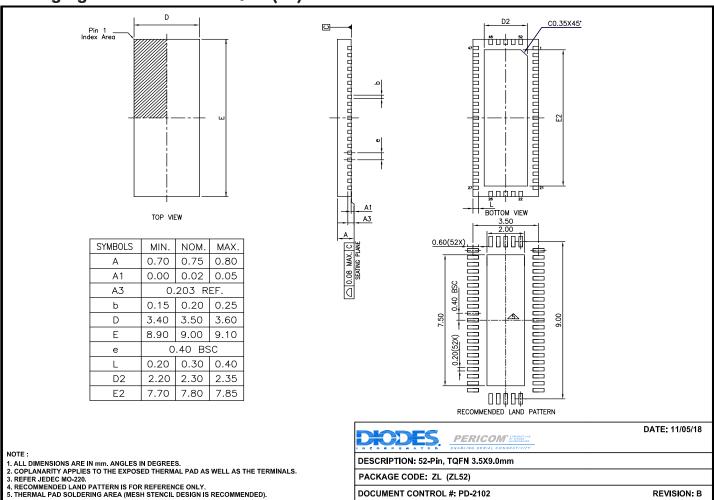


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# Packaging Mechanical: 52-TQFN (ZL)



#### For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

### **Ordering Information**

Ordering Code	Packaging Code	Package Description
PI2DDR3212ZLEX	ZL	52-Pin, Thin Quad Flat No-Lead (TQFN)
PI2DDR3212NCEX NC		48-Pin, Thin Fine Pitch Ball Grid Array (TFBGA)

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel





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